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Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.32 \text{ V}$ at $I_F = 5.0 \text{ A}$





PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V_{RRM}	60 V			
I _{FSM}	200 A			
V _F at I _F = 15 A	0.45 V			
T _J max.	150 °C			
Package	TO-263AB			
Diode variation	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Not recommended for PCB bottom side wave mounting
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

J-51D-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT30L60C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	60	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	А	
	per diode		15		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	200	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MIN.	UNIT
Instantaneous forward voltage per diode	I _F = 5.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.43	-	V
	I _F = 7.5 A			0.46	-	
	I _F = 15 A			0.51	0.60	
	I _F = 5.0 A	T _A = 125 °C		0.32	-	
	I _F = 7.5 A			0.36	-	
	I _F = 15 A			0.45	0.57	
Reverse current per diode	$V_{\rm P} = 60 \text{ V}$	T _A = 25 °C	I _R ⁽²⁾	-	4.0	- mA
		T _A = 125 °C		27	110	

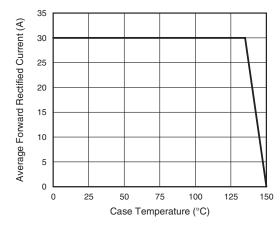
Notes

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT30L60C	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.8	°C/W	
	per device		0.8] 0/11	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT30L60C-E3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VBT30L60C-E3/8W	1.39	8W	800/reel	Tape and reel	
TO-263AB	VBT30L60C-M3/I	1.39	I	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





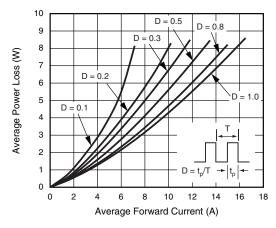


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle



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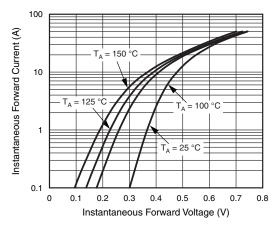


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

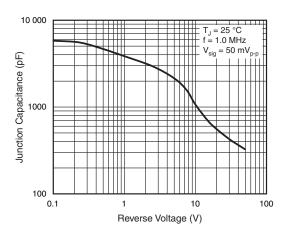


Fig. 5 - Typical Junction Capacitance Per Diode

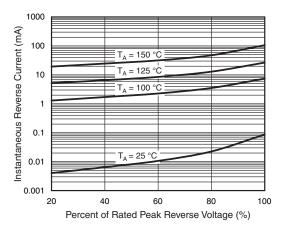


Fig. 4 - Typical Reverse Characteristics Per Diode

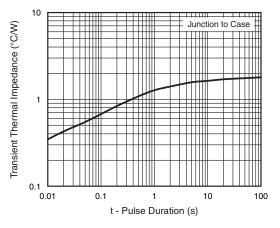
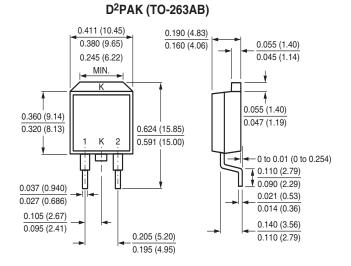
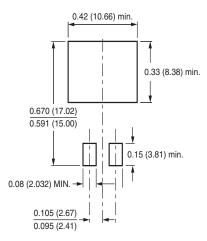


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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